

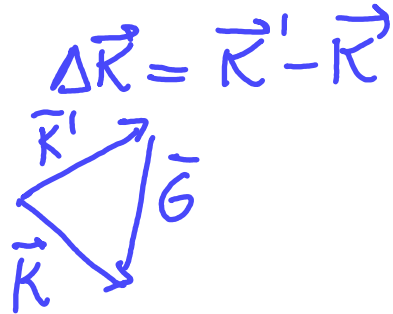
Scattering

Lecture 2

Recap

Bragg Law: $2d \sin \theta = n \lambda$

Laue Condition: $\Delta \vec{k} = \vec{G} \rightarrow$ Elastic scattering

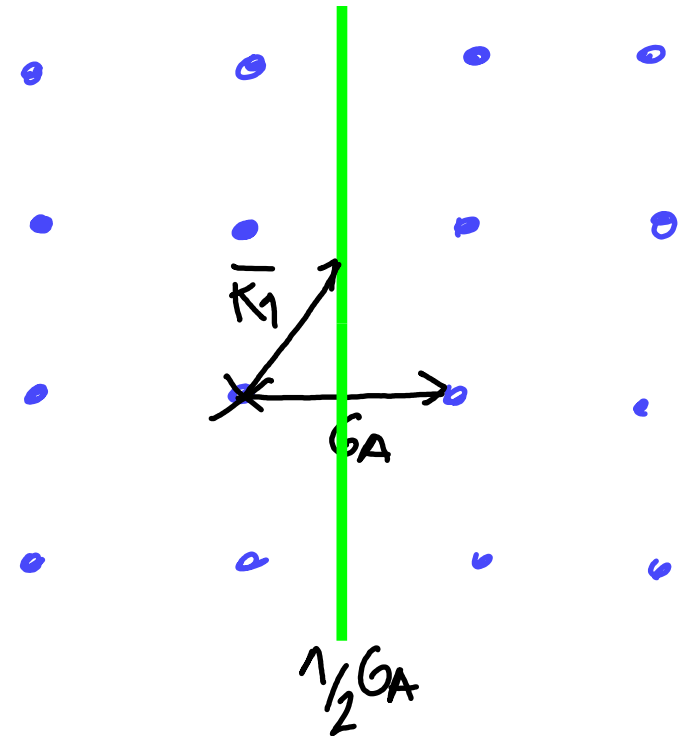
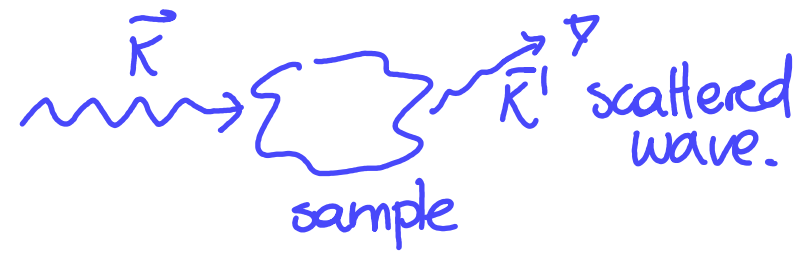


$$2\vec{k} \cdot \vec{G} = G^2$$

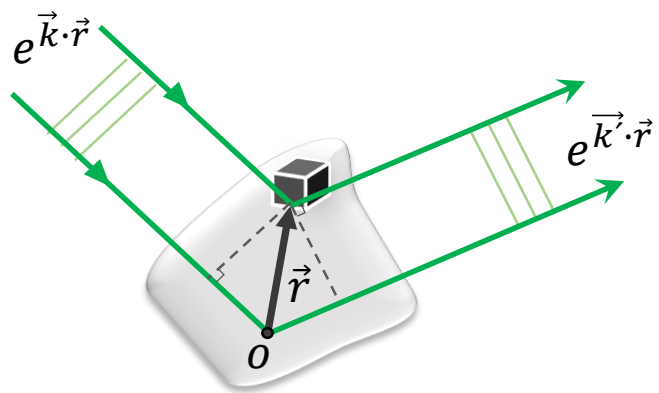
$$\vec{k} \cdot \left(\frac{1}{2}\vec{G}\right) = \left(\frac{1}{2}G\right)^2$$

EX. $\vec{k}_1 \cdot \left(\frac{1}{2}\vec{G}_A\right) = \left(\frac{1}{2}G_A\right)^2$

Special role of the Brillouin zone (border)!



Structure Factor



Total Amplitude of the scattered wave in the direction \vec{k}'

$$F = \int_V n(\vec{r}) e^{i(\vec{k} - \vec{k}') \cdot \vec{r}} dV$$

$\underbrace{\qquad\qquad\qquad}_{= -\Delta\vec{k}}$
 over sample volume

For a crystal of N cells,
 and when $\Delta\vec{k} = \vec{G}$ is satisfied for a
 direction $\vec{G} = h\vec{b}_1 + k\vec{b}_2 + l\vec{b}_3$,

$$F_{\vec{G}} = N \int_{\text{cell}} n(\vec{r}) \cdot e^{-i\vec{G} \cdot \vec{r}} d^3r \equiv N \cdot S_{\vec{G}}$$

$S_{\vec{G}} = S_{hkl} = \text{Structure Factor}$

notice that $I_{\vec{k}} \propto |S_{hkl}|^2$

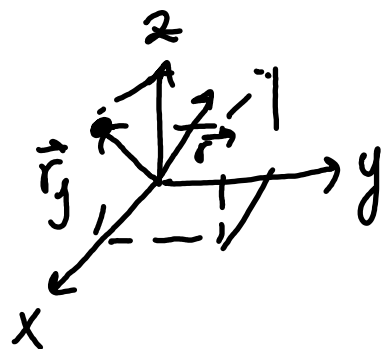
$$F = \sum_{\vec{G}} \int dV n_{\vec{G}} \exp(i(\vec{G} \cdot \Delta\vec{K}) \cdot \vec{r})$$

for $\Delta\vec{K} = \vec{G} \Rightarrow F = V \cdot n_{\vec{G}}$

(if $\Delta\vec{K} \neq \vec{G} \Rightarrow F$ is very small)

Atomic form factor

→ decompose $n(\vec{r})$ in atomic contributions within a cell :



• $n_j(\vec{r}-\vec{r}_j)$

• electron density at \vec{r} : $n(\vec{r}) = \sum_j^s n_j(\vec{r}-\vec{r}_j)$

atoms in the basis

$$S_{\vec{G}} = \int_{\text{cell}} n(\vec{r}) \cdot e^{-i\vec{G}\cdot\vec{r}} d^3r = \sum_j \int_{\text{cell}} n_j(\vec{r}-\vec{r}_j) e^{-i\vec{G}\cdot\vec{r}} d^3r$$

define $\vec{\rho} = \vec{r} - \vec{r}_j$

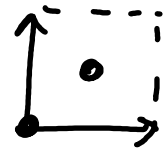


$$S_{\vec{G}} = \sum_j \int_{\text{cell}} n_j(\vec{\rho}) e^{-i\vec{G}\cdot\vec{\rho}} e^{-i\vec{G}\cdot\vec{r}_j} d^3\rho = \sum_j e^{-i\vec{G}\cdot\vec{r}_j} \underbrace{\int n_j(\vec{\rho}) e^{-i\vec{G}\cdot\vec{\rho}} d^3\rho}_{= f_j = \text{Atomic Form Factor}} = \sum_j e^{-i\vec{G}\cdot\vec{r}_j} \cdot f_j$$

structure factor

if we consider point-like atoms: $n_j(\vec{\rho}) = Z\delta(\vec{\rho}) \rightarrow f_j = Z$

position atoms of the basis within the (real) cell:



$$\vec{r}_j = x_j \bar{a}_1 + y_j \bar{a}_2 + z_j \bar{a}_3$$

$$0 \leq x_j, y_j, z_j \leq 1$$

A reflexion $h, k, l \rightarrow$ correspond to $\vec{G} = h\bar{b}_1 + k\bar{b}_2 + l\bar{b}_3$

$$S_{\vec{G}} = S_{hkl} = \sum_j e^{-i\vec{G} \cdot \vec{r}_j} \cdot f_j = \sum_j e^{-i2\pi(hx_j + ky_j + lz_j)} \cdot f_j$$

↑
structure
Factor

$$\bar{b}_i \cdot \bar{a}_j = 2\pi \delta_{ij}$$

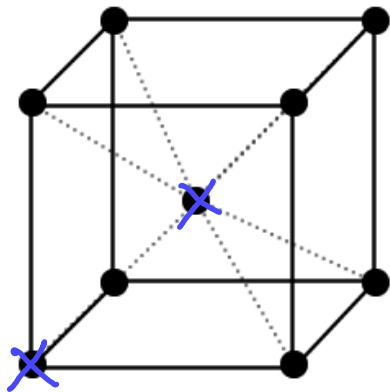
$$(\delta_{ij} = 0 \text{ } i \neq j, \delta_{ij} = 1 \text{ } i = j)$$

Atomic
Form
Factor

it tells us with scattering
peaks will be absent for a
given lattice!

see examples →

Structure factor for a monoatomic bcc



I (Body)

simple cubic cell
with a basis of 2 identical atoms @ $(0, 0, 0)$, $(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$

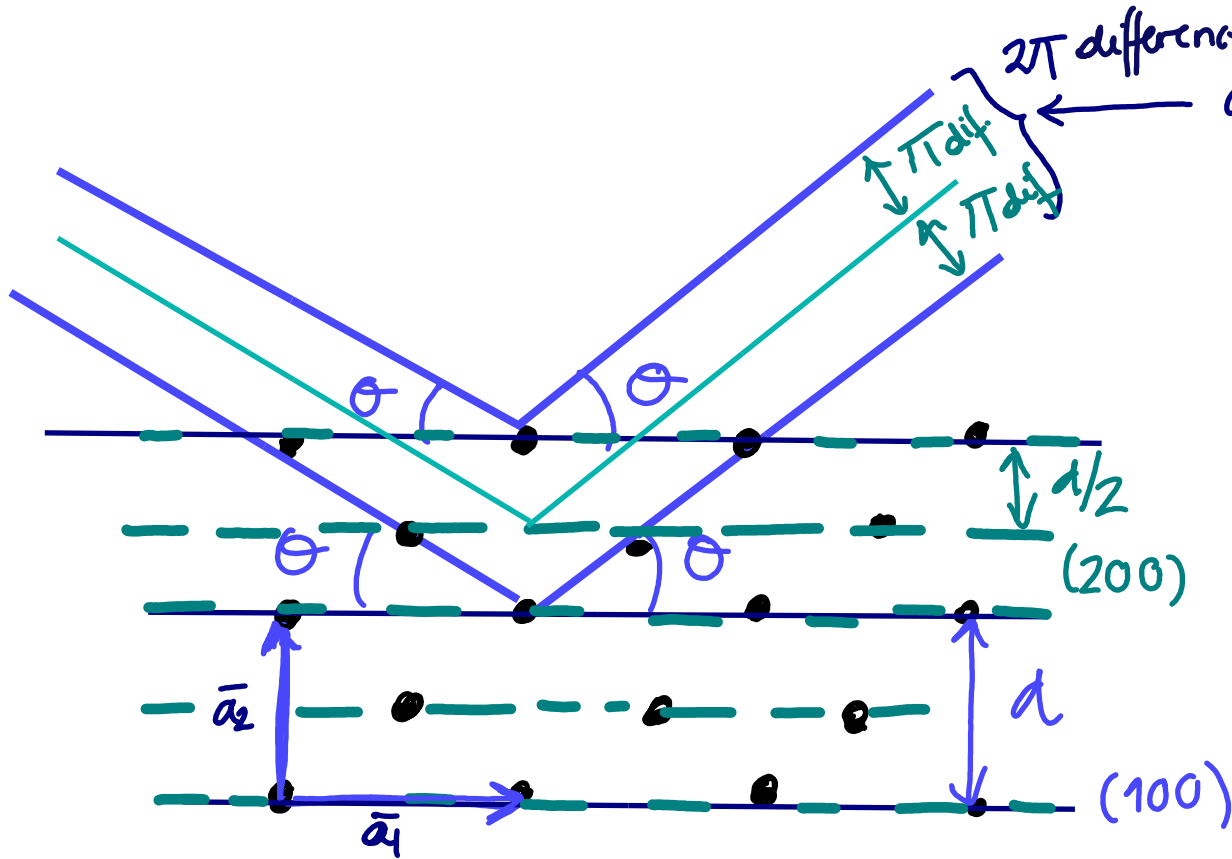
$\begin{matrix} \uparrow & \uparrow & \uparrow \\ x_1 & y_1 & z_1 \end{matrix}$
 $\begin{matrix} \uparrow & \uparrow & \uparrow \\ x_2 & y_2 & z_2 \end{matrix}$

$$\begin{aligned}
 S_{hkl} &= \sum_j e^{-i2\pi(hx_j + Ky_j + lz_j)} \cdot f_j = \\
 &= f \cdot (e^{-i2\pi \cdot 0} + e^{-i\pi(h+k+l)}) = \\
 &= f \cdot (1 + (-1)^{h+k+l})
 \end{aligned}$$

For a BCC $\left\{ \begin{array}{ll} S_{hkl} = 0 & \text{when } h+k+l = \text{odd integer} \\ S_{hkl} = 2f & \text{" } h+k+l = \text{even integer} \end{array} \right.$

Geometric interpretation of the selection rules

we work with orthogonal axis cell instead of a more complex non orthogonal \Rightarrow some Miller indices do not correspond to families of planes

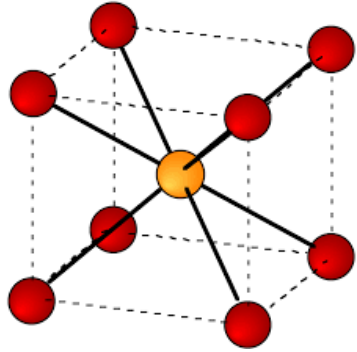


constructive interference expected for the simple cubic (100)

BCC : additional plane at $\frac{1}{2}a$
 \Rightarrow it causes destructive interference

\Rightarrow (100) is absent in bcc

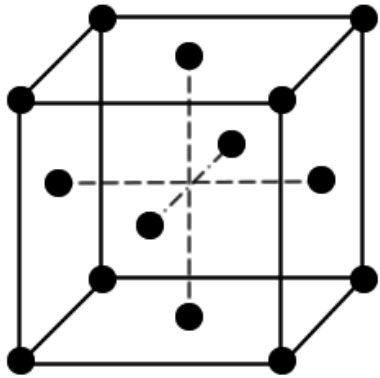
Structure factor for CsCl



simple cubic + $\begin{cases} \text{Cs} & [0, 0, 0] \\ \text{Cl} & [\frac{1}{2}, \frac{1}{2}, \frac{1}{2}] \end{cases}$

$$\begin{aligned} S_{hkl} &= \sum_j e^{-i2\pi(hx_j + ky_j + lz_j)} \cdot f_j = \\ &= f_{\text{Cs}} + f_{\text{Cl}} e^{-i\pi(h+k+l)} = \\ &= f_{\text{Cs}} + f_{\text{Cl}} (-1)^{h+k+l} \end{aligned}$$

Structure factor for a monoatomic fcc



F (Face)

simple cubic with 4 atoms basis

$$\begin{array}{ccc} x_1 & y_1 & z_1 \\ | & | & | \\ (0, 0, 0) & , & (\frac{1}{2}, \frac{1}{2}, 0) \\ (\frac{1}{2}, 0, \frac{1}{2}) & , & (0, \frac{1}{2}, \frac{1}{2}) \end{array}$$

$$S_{hkl} = \sum_j e^{-i2\pi(hx_j + ky_j + lz_j)} \cdot f_j$$

$$S_{hkl} = f \cdot \left(1 + \underbrace{e^{-i\pi(h+k)}}_{\pm 1} + \underbrace{e^{-i\pi(h+l)}}_{\pm 1} + \underbrace{e^{-i\pi(k+l)}}_{\pm 1} \right)$$

$$\vec{G} = h\vec{b}_1 + k\vec{b}_2 + l\vec{b}_3$$

atoms basis

$$\vec{r}_j = x_j\vec{a}_1 + y_j\vec{a}_2 + z_j\vec{a}_3$$

For FCC $S_{hkl} \neq 0$ only if all h, k, l are odd
all h, k, l are even

FCS $S_{hkl} \neq 0$ except if h, k, l are all odd or all even

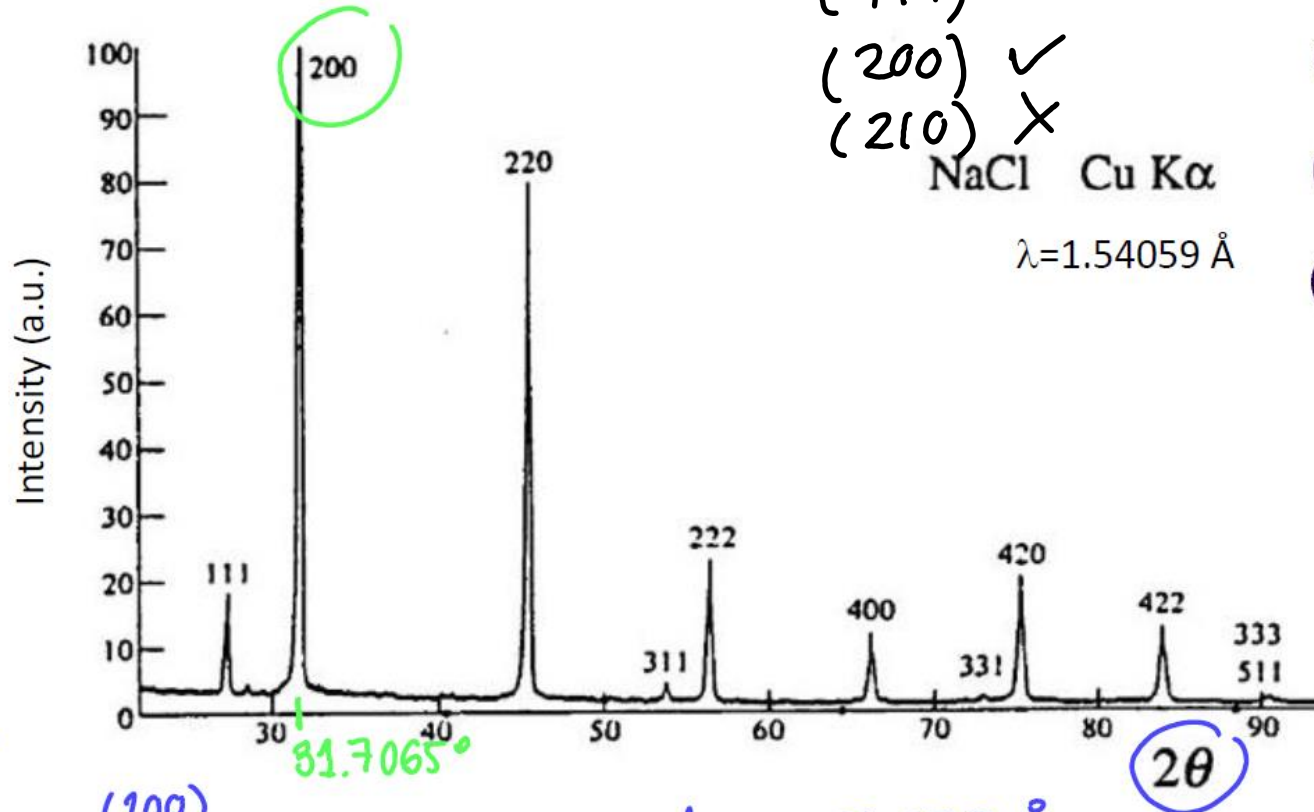
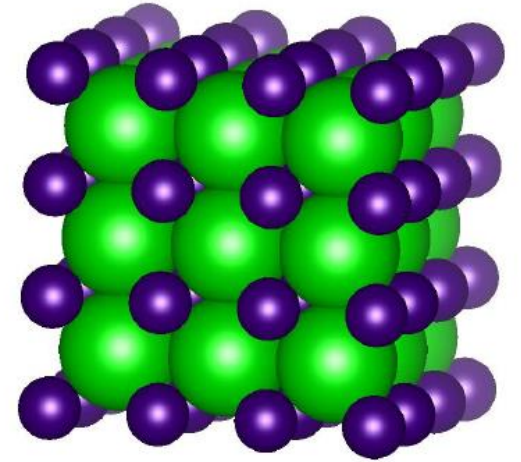
Previous class

Determine the lattice parameter for NaCl

- (100) X
- (110) X
- (111) ✓
- (200) ✓
- (210) X

NaCl Cu K α

$\lambda = 1.54059 \text{ \AA}$



$$2d \sin \theta = n \lambda$$

$$d = \frac{n \lambda}{2 \sin \theta}$$

(200)
 \longrightarrow
 $n=2$

lattice parameter = 5.639 \AA

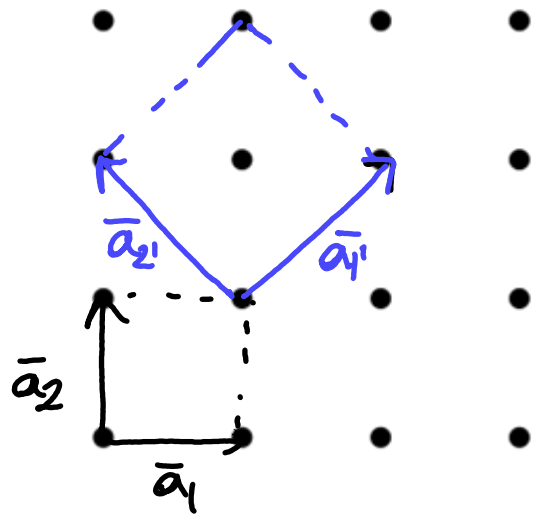
Systematic absences of scattering

"Selection Rules" : which peaks must be absent for a given lattice
(other peaks can vanish due to the details of the basis)

Crystal structure	Condition for peak to occur
Simple cubic	All h, k, l allowed
bcc	$h + k + l$ must be even
fcc	h, k, l must be all odd or all even

$$S_{hke} = S_{(hke)}^{\text{lattice}} \times S_{(hke)}^{\text{basis}} \longrightarrow \text{see exercises}$$

Does the arbitrary choice of lattice vectors influence the reciprocal lattice and the diffraction pattern?



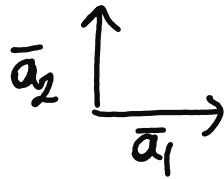
Real lattice: 2 \neq sets of lattice vector chosen $(\bar{a}_1/\bar{a}_2; \bar{a}_1'/\bar{a}_2')$



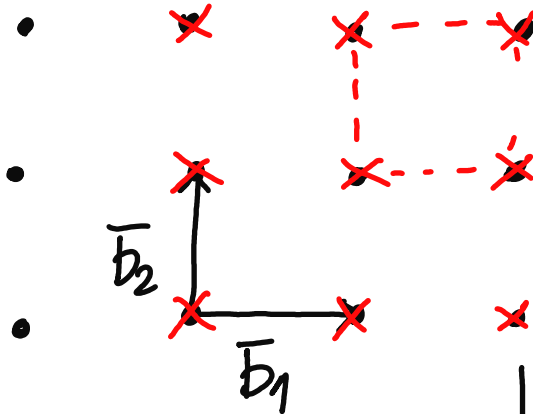
Same diffraction pattern independently of the choice



Primitive square



Real lattice
 $|a_1| < |a_1'|$



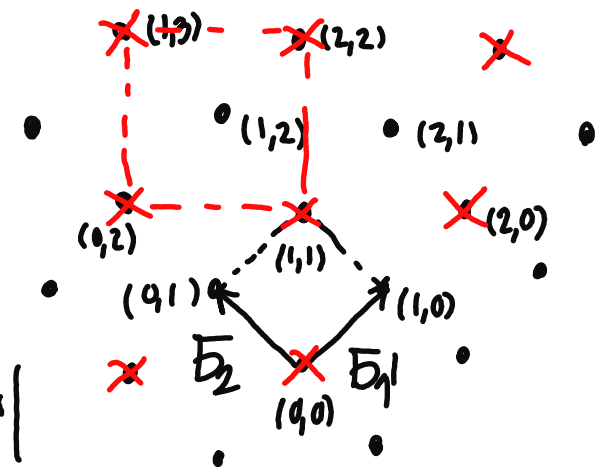
$S = f_0$ for all hkl

Centered square



Recip. Latt.

$|b_1| > |b_1'|$

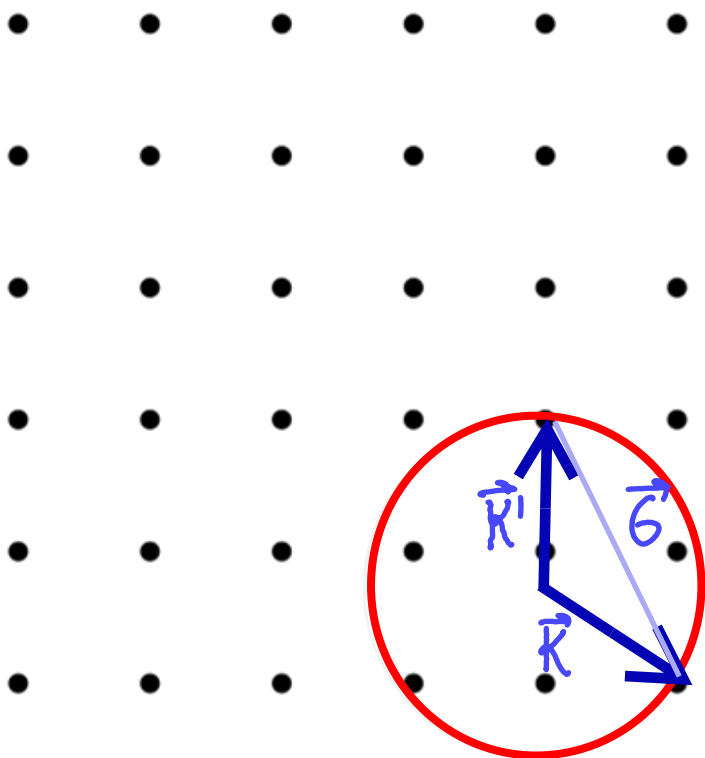


$S = 2f_0$ for $h+k+l = \text{even}$
 $S = 0$ for $h+k+l = \text{odd}$

X diffraction max.

Methods of Scattering experiments

Ewald construction for diffraction

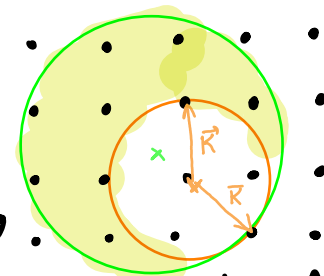


R.L.

$$K = \frac{2\pi}{\lambda}$$

Diffraction condition $\Delta \vec{R} = \vec{G}$

⇒ Probability to obtain a diffraction spot is low

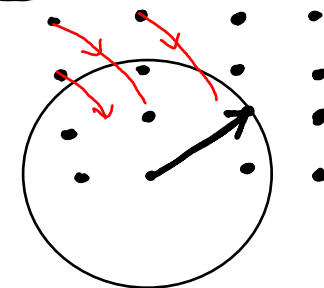


Methods

* Laue Method

(range of λ instead of a monochromatic incident wave)

* Rotating Crystal Method



Ewald sphere

